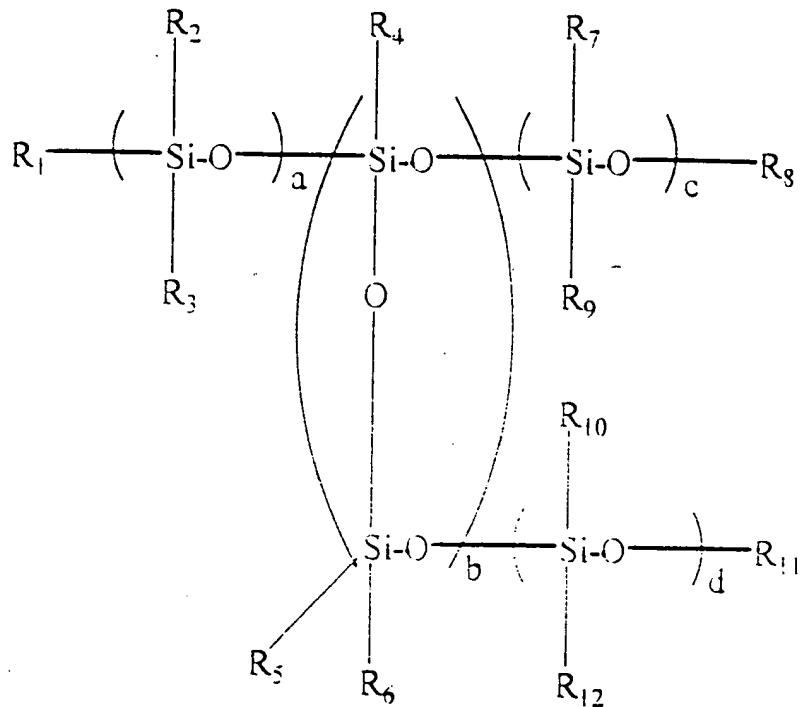


IN THE CLAIMS:

Kindly amend Claims 1 and 7 and cancel Claims 5 and 6 as follows:

1. (Currently Amended) An electricity accumulating element comprising a pair of electrodes, and a dielectric thin film and a solid electrolyte thin film sandwiched between the electrodes, wherein the dielectric thin film is a metal oxide thin film and the solid electrolyte thin film is a thin film obtained by firing at a temperature of 200 °C or more a silicon-containing compound comprising at least one member selected from the group consisting of a polysilane which is soluble in organic solvent and a silicone compound having a chemical structure represented by the general formula:



wherein R₁ to R₁₂, which may be the same or different, are each a group selected from the group consisting of an aliphatic hydrocarbon which has 1 to 10 carbon atoms and may be substituted with a halogen or a glycidyloxy group, an aromatic hydrocarbon group having 6 to 12 carbon atoms, and an alkoxy group having 1 to 8 carbon atoms; a, b, c and d are each an integer of 0 or more; and a + b + c + d ≥ 1.

2. (Previously Presented) the electricity accumulating element according to claim 1,
wherein the thickness of the metal oxide thin film is from 1 to 100 nm.
3. (Previously Presented) The electricity accumulating element according to claim 1,
wherein the metal oxide thin film is a chromium oxide thin film.
4. (Previously Presented) The electricity accumulating element according to claim 3,
wherein the chromium oxide thin film is a film obtained by subjecting a chromium nitrogen oxide thin film to heat treatment at a temperature of 400 to 800 ° C.
5. (Cancelled)
6. (Cancelled)
7. (Currently Amended) The electricity accumulating element according to claim 6 1,
wherein the silicon-containing compound further comprises a silicon compound and at least one selected from a peroxide and a benzphenone derivative having a benzophenone structure.